

# BAT760 Medium power Schottky barrier single diode Rev. 03 – 17 October 2008

**Product data sheet** 

## 1. Product profile

### 1.1 General description

Planar medium power Schottky barrier single diode with an integrated guard ring for stress protection, encapsulated in a SOD323 (SC-76) very small Surface-Mounted Device SMD plastic package.

### **1.2 Features**

- Ultra high-speed switching
- Very low forward voltage
- Guard-ring protected
- Very small SMD plastic package

### **1.3 Applications**

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

### 1.4 Quick reference data

#### Table 1. Quick reference data

| Symbol         | Parameter       | Conditions           | Min        | Тур | Max | Unit |
|----------------|-----------------|----------------------|------------|-----|-----|------|
| V <sub>R</sub> | reverse voltage |                      | -          | -   | 20  | V    |
| I <sub>F</sub> | forward current |                      | -          | -   | 1   | А    |
| V <sub>F</sub> | forward voltage | I <sub>F</sub> = 1 A | <u>[1]</u> | 480 | 550 | mV   |



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# 2. Pinning information

| Table 2. | Pinning     |                   |                   |
|----------|-------------|-------------------|-------------------|
| Pin      | Description | Simplified outlin | ne Graphic symbol |
| 1        | cathode     | [1]               | 64                |
| 2        | anode       |                   | 1 🕂 2             |
|          |             |                   | sym001            |

[1] The marking bar indicates the cathode.

# 3. Ordering information

| Table 3.         Ordering information |         |  |         |  |  |
|---------------------------------------|---------|--|---------|--|--|
| Type number                           | Package |  |         |  |  |
|                                       | Name    | Description                              | Version |  |  |
| BAT760                                | SC-76   | plastic surface-mounted package; 2 leads | SOD323  |  |  |

## 4. Marking

| Table 4. Marking codes |              |
|------------------------|--------------|
| Type number            | Marking code |
| BAT760                 | A4           |

## 5. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

|                  |  | 0,                    | ,   |      |      |
|------------------|--|---|-----|------|------|
| Symbol           | Parameter                              | Conditions  | Min | Max  | Unit |
| V <sub>R</sub>   | reverse voltage                        |   | -   | 20   | V    |
| I <sub>F</sub>   | forward current                        |   | -   | 1    | А    |
| I <sub>FSM</sub> | non-repetitive peak<br>forward current | t <sub>p</sub> = 8.3 ms;<br>half-sine wave;<br>JEDEC method | -   | 5    | A    |
| Tj               | junction temperature                   |   | -   | 125  | °C   |
| T <sub>amb</sub> | ambient temperature                    |   | -65 | +125 | °C   |
| T <sub>stg</sub> | storage temperature                    |   | -65 | +150 | °C   |
|                  |  |   |     |      |      |

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### 6. Thermal characteristics

| Table 6.             | Thermal characteristics                     |                                    |              |     |     |      |
|----------------------|---|------------------------------------|--------------|-----|-----|------|
| Symbol               | Parameter                                   | Conditions                         | Min          | Тур | Max | Unit |
| R <sub>th(j-a)</sub> | thermal resistance from junction to ambient | hermal resistance from in free air |              |     |     |      |
|                      |   |                                    | <u>[1]</u> _ | -   | 220 | K/W  |
|                      |   |                                    | [2]          | -   | 180 | K/W  |
|                      |   |                                    |              |     |     |      |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode  $10 \times 10$  mm<sup>2</sup>.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode  $40 \times 40$  mm<sup>2</sup>.

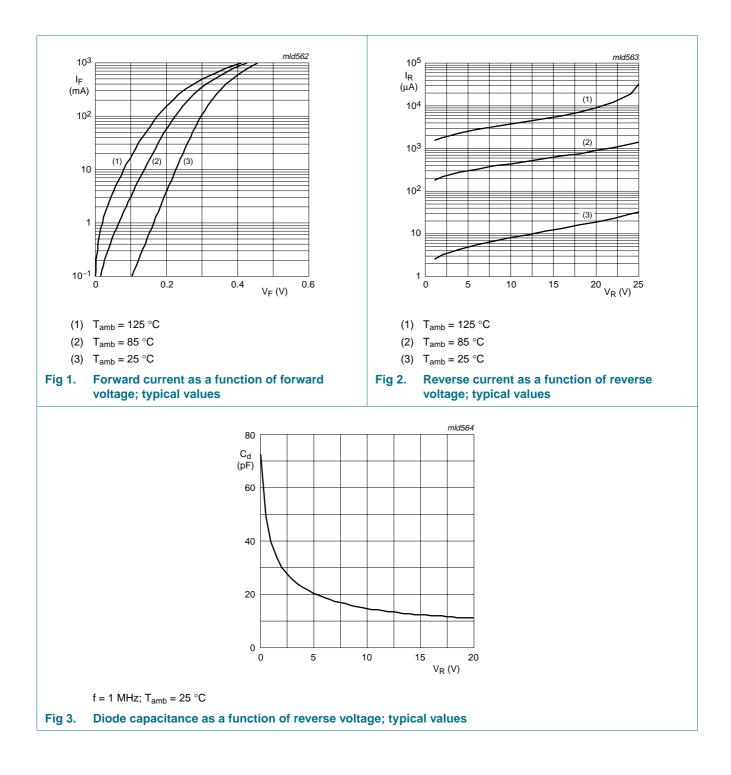
### 7. Characteristics

### Table 7. Characteristics

 $T_{amb} = 25 \circ C$  unless otherwise specified.

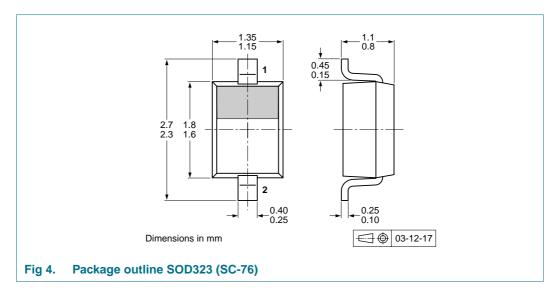
| Symbol         | Parameter         | Conditions                      | Min        | Тур | Max | Unit |
|----------------|-------------------|---------------------------------|------------|-----|-----|------|
| VF             | forward voltage   |                                 | <u>[1]</u> |     |     |      |
|                |                   | I <sub>F</sub> = 10 mA          | -          | 240 | 270 | mV   |
|                |                   | I <sub>F</sub> = 100 mA         | -          | 300 | 350 | mV   |
|                |                   | I <sub>F</sub> = 1 A            | -          | 480 | 550 | mV   |
| I <sub>R</sub> | reverse current   |                                 | <u>[1]</u> |     |     |      |
|                |                   | V <sub>R</sub> = 5 V            | -          | 5   | 10  | μΑ   |
|                |                   | V <sub>R</sub> = 8 V            | -          | 7   | 20  | μΑ   |
|                |                   | V <sub>R</sub> = 15 V           | -          | 10  | 50  | μΑ   |
| C <sub>d</sub> | diode capacitance | V <sub>R</sub> = 5 V; f = 1 MHz | -          | 19  | 25  | pF   |

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## 8. Package outline



# 9. Packing information

#### Table 8. Packing methods

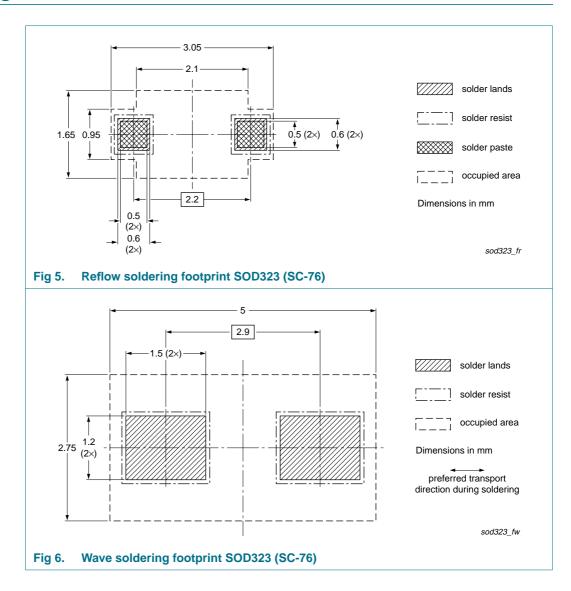
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                    | Packing quantity |       |
|-------------|---------|--------------------------------|------------------|-------|
|             |         |                                | 3000             | 10000 |
| BAT760      | SOD323  | 4 mm pitch, 8 mm tape and reel | -115             | -135  |

[1] For further information and the availability of packing methods, see Section 13.

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## **10. Soldering**



### Medium power Schottky barrier single diode

# 11. Revision history

| Document ID    | Release date                    | Data sheet status                                  | Change notice         | Supersedes            |
|----------------|---------------------------------|--|-----------------------|-----------------------|
| BAT760_3       | 20081017                        | Product data sheet                                 | -                     | BAT760_2              |
| Modifications: |                                 | of this data sheet has been of NXP Semiconductors. | redesigned to comply  | with the new identity |
|                | <ul> <li>Legal texts</li> </ul> | have been adapted to the r                         | new company name w    | here appropriate.     |
|                | Table 1 "Qu                     | iick reference data": added                        |                       |                       |
|                | • Figure 4: s                   | uperseded by minimized pa                          | ckage outline drawing |                       |
|                | Section 9 "                     | Packing information": added                        | 1                     |                       |
|                | Section 10                      | "Soldering": added                                 |                       |                       |
|                | Section 12                      | "Legal information": update                        | d                     |                       |
| BAT760_2       | 20040126                        | Product specification                              | -                     | BAT760_1              |
| BAT760 1       | 20010312                        | Product specification                              | -                     | -                     |

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## **12. Legal information**

### 12.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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